



# PHPT610030NK

NPN/NPN high power double bipolar transistor

10 September 2020

Product data sheet

## 1. General description

NPN/NPN high power double bipolar transistor in a SOT1205 (LFPAK56D) Surface-Mounted Device (SMD) power plastic package.

PNP/PNP complement: PHPT610030PK

NPN/PNP complement: PHPT610030NPK

## 2. Features and benefits

- High thermal power dissipation capability
- Suitable for high temperature applications up to 175 °C
- Reduced Printed-Circuit Board (PCB) requirements comparing to transistors in DPAK
- High energy efficiency due to less heat generation
- AEC-Q101 qualified

## 3. Applications

- Motor control
- Power management
- Load switch
- Linear mode voltage regulator
- Backlighting applications
- Relay replacement

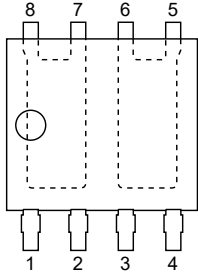
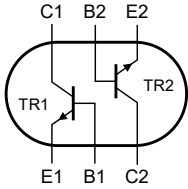
## 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Per transistor</b>						
$V_{CEO}$	collector-emitter voltage	open base	-	-	100	V
$I_C$	collector current		-	-	3	A
$R_{CEsat}$	collector-emitter saturation resistance	$I_C = 3\text{ A}$ ; $I_B = 0.3\text{ A}$ ; $t_p \leq 300\ \mu\text{s}$ ; pulsed; $\delta \leq 0.02$ ; $T_{amb} = 25\text{ °C}$	-	75	110	m $\Omega$

## 5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	E1	emitter TR1	 <p>LFPAK56D; Dual LFPAK (SOT1205)</p>	 <p>sym140</p>
2	B1	base TR1		
3	E2	emitter TR2		
4	B2	base TR2		
5	C2	collector TR2		
6	C2	collector TR2		
7	C1	collector TR1		
8	C1	collector TR1		

## 6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PHPT610030NK	LFPAK56D; Dual LFPAK	plastic, single ended surface mounted package (LFPAK56D); 8 leads	SOT1205

## 7. Marking

Table 4. Marking codes

Type number	Marking code
PHPT610030NK	10030NK

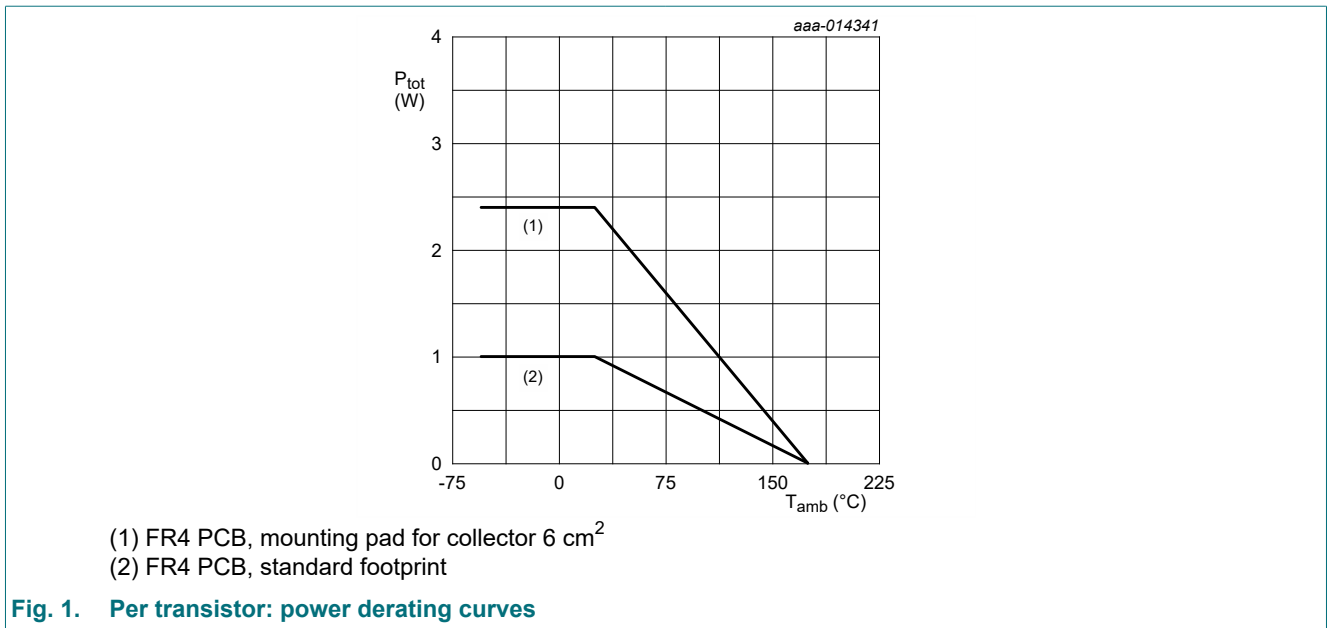
## 8. Limiting values

**Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
<b>Per transistor</b>						
$V_{CBO}$	collector-base voltage	open emitter		-	100	V
$V_{CEO}$	collector-emitter voltage	open base		-	100	V
$V_{EBO}$	emitter-base voltage	open collector		-	7	V
$I_C$	collector current			-	3	A
$I_{CM}$	peak collector current	single pulse; $t_p \leq 1$ ms		-	8	A
$I_B$	base current			-	0.5	A
$P_{tot}$	total power dissipation	$T_{amb} \leq 25$ °C	[1]	-	1	W
			[2]	-	2.4	W
			[3]	-	25	W
<b>Per device</b>						
$P_{tot}$	total power dissipation	$T_{amb} \leq 25$ °C	[1]	-	1.25	W
			[4]	-	5	W
			[2]	-	3	W
$T_j$	junction temperature			-	175	°C
$T_{amb}$	ambient temperature			-55	175	°C
$T_{stg}$	storage temperature			-65	175	°C

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>.
- [3] Power dissipation from junction to mounting base.
- [4] Device mounted on a ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint.



### 9. Thermal characteristics

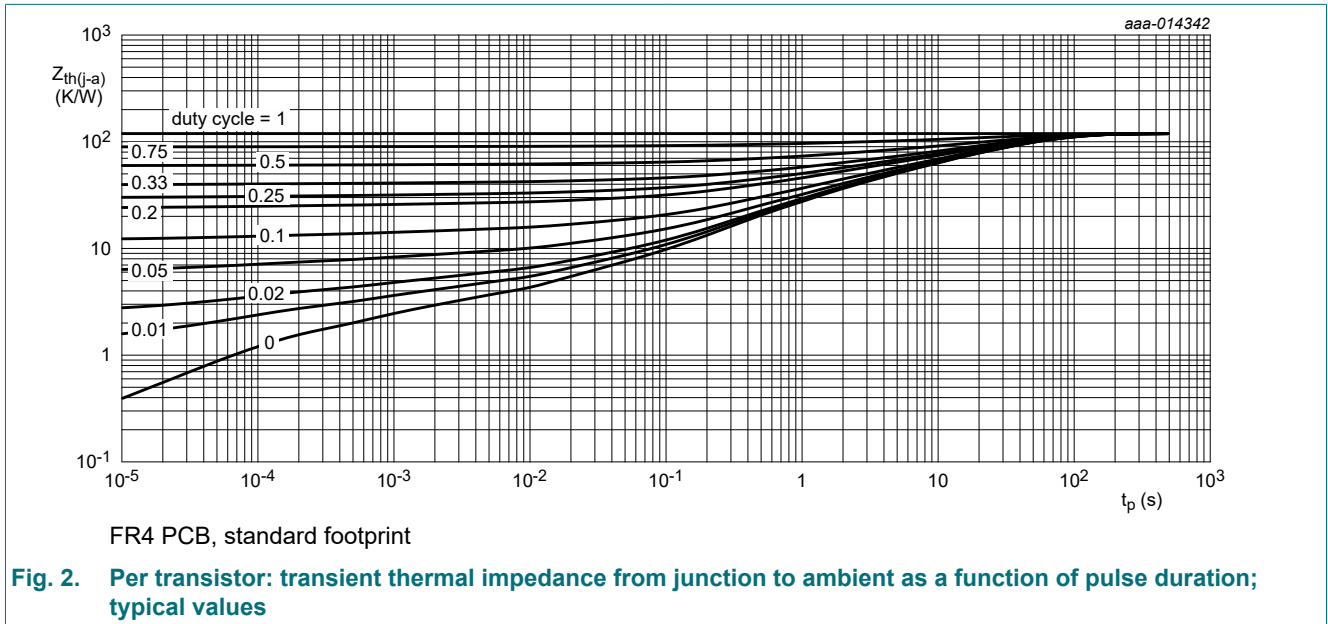
Table 6. Thermal characteristics

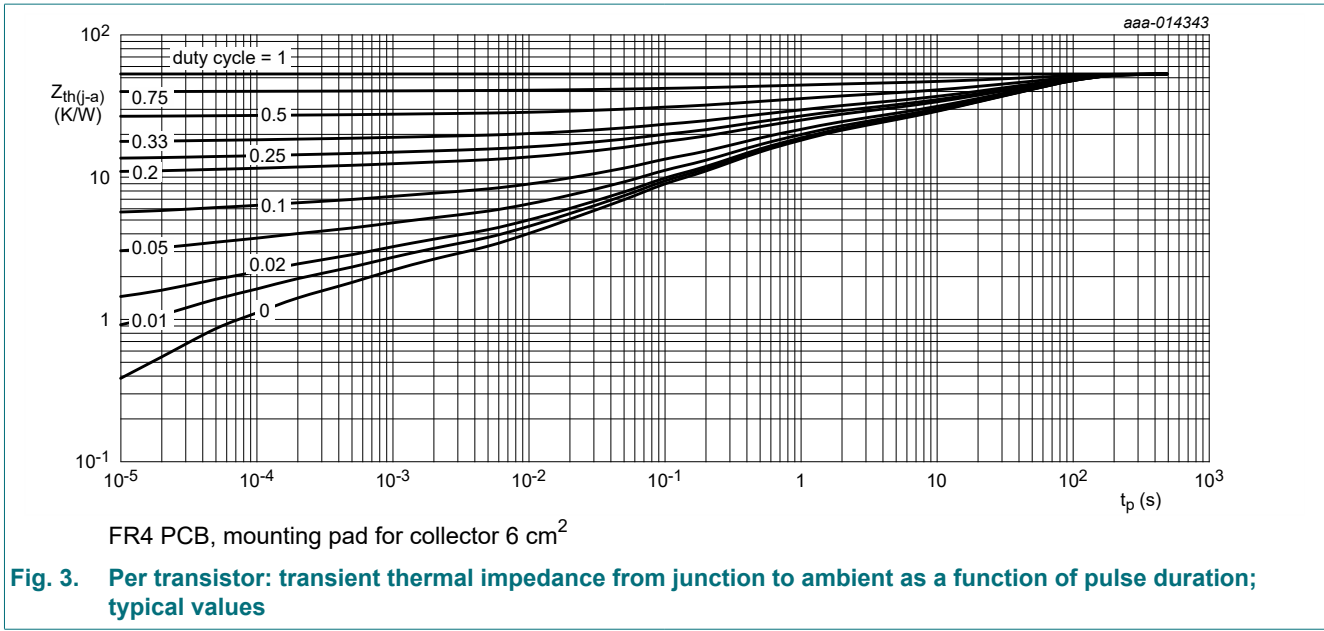
Symbol	Parameter	Conditions		Min	Typ	Max	Unit
<b>Per transistor</b>							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	150	K/W
			[2]	-	-	62.5	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point			-	-	6	K/W
<b>Per device</b>							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	120	K/W
			[2]	-	-	50	K/W
			[3]	-	-	30	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm<sup>2</sup>.

[3] Device mounted on a ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint.

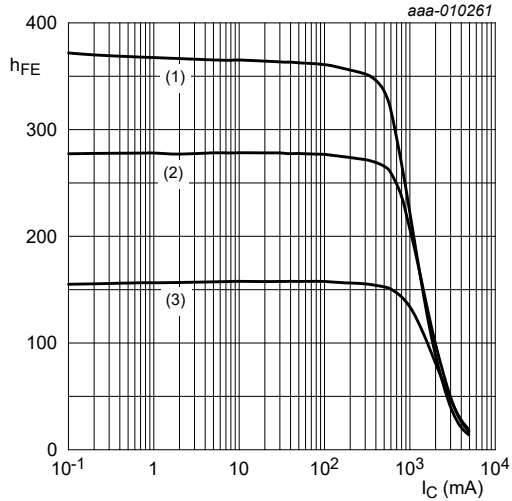




## 10. Characteristics

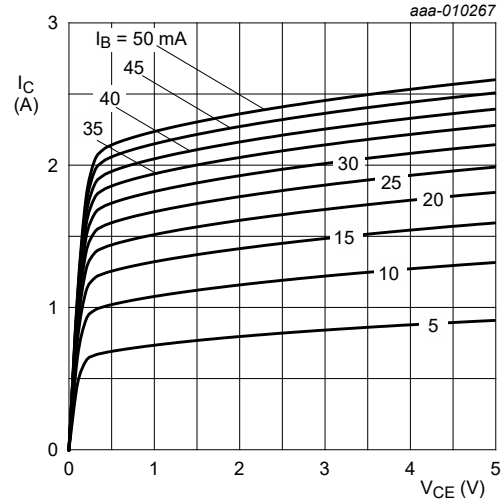
Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Per transistor</b>						
$I_{CBO}$	collector-base cut-off current	$V_{CB} = 80\text{ V}; I_E = 0\text{ A}; T_{amb} = 25\text{ }^\circ\text{C}$	-	-	100	nA
		$V_{CB} = 80\text{ V}; I_E = 0\text{ A}; T_j = 150\text{ }^\circ\text{C}$	-	-	50	$\mu\text{A}$
$I_{CES}$	collector-emitter cut-off current	$V_{CE} = 80\text{ V}; V_{BE} = 0\text{ V}; T_{amb} = 25\text{ }^\circ\text{C}$	-	-	100	nA
$I_{EBO}$	emitter-base cut-off current	$V_{EB} = 7\text{ V}; I_C = 0\text{ A}; T_{amb} = 25\text{ }^\circ\text{C}$	-	-	100	nA
$h_{FE}$	DC current gain	$V_{CE} = 10\text{ V}; I_C = 500\text{ mA}; t_p \leq 300\text{ }\mu\text{s};$ pulsed; $\delta \leq 0.02; T_{amb} = 25\text{ }^\circ\text{C}$	150	250	-	
		$V_{CE} = 10\text{ V}; I_C = 1\text{ A}; t_p \leq 300\text{ }\mu\text{s};$ pulsed; $\delta \leq 0.02; T_{amb} = 25\text{ }^\circ\text{C}$	80	250	-	
		$V_{CE} = 10\text{ V}; I_C = 2\text{ A}; t_p \leq 300\text{ }\mu\text{s};$ pulsed; $\delta \leq 0.02; T_{amb} = 25\text{ }^\circ\text{C}$	20	100	-	
		$V_{CE} = 10\text{ V}; I_C = 3\text{ A}; t_p \leq 300\text{ }\mu\text{s};$ pulsed; $\delta \leq 0.02; T_{amb} = 25\text{ }^\circ\text{C}$	10	40	-	
$V_{CEsat}$	collector-emitter saturation voltage	$I_C = 1\text{ A}; I_B = 50\text{ mA}; t_p \leq 300\text{ }\mu\text{s};$ pulsed; $\delta \leq 0.02; T_{amb} = 25\text{ }^\circ\text{C}$	-	90	150	mV
		$I_C = 3\text{ A}; I_B = 300\text{ mA}; t_p \leq 300\text{ }\mu\text{s};$ pulsed; $\delta \leq 0.02; T_{amb} = 25\text{ }^\circ\text{C}$	-	225	330	mV
$R_{CEsat}$	collector-emitter saturation resistance	$I_C = 3\text{ A}; I_B = 0.3\text{ A}; t_p \leq 300\text{ }\mu\text{s};$ pulsed; $\delta \leq 0.02; T_{amb} = 25\text{ }^\circ\text{C}$	-	75	110	$\text{m}\Omega$
$V_{BEsat}$	base-emitter saturation voltage	$I_C = 1\text{ A}; I_B = 50\text{ mA}; t_p \leq 300\text{ }\mu\text{s};$ pulsed; $\delta \leq 0.02; T_{amb} = 25\text{ }^\circ\text{C}$	-	0.86	1	V
		$I_C = 2\text{ A}; I_B = 200\text{ mA}; t_p \leq 300\text{ }\mu\text{s};$ pulsed; $\delta \leq 0.02; T_{amb} = 25\text{ }^\circ\text{C}$	-	1	1.2	V
$V_{BEon}$	base-emitter turn-on voltage	$V_{CE} = 2\text{ V}; I_C = 0.1\text{ A}; t_p \leq 300\text{ }\mu\text{s};$ pulsed; $\delta \leq 0.02; T_{amb} = 25\text{ }^\circ\text{C}$	-	0.67	0.85	V
$t_d$	delay time	$V_{CC} = 12.5\text{ V}; I_C = 1\text{ A}; I_{B(on)} = 50\text{ mA};$ $I_{B(off)} = -50\text{ mA}; T_{amb} = 25\text{ }^\circ\text{C}$	-	20	-	ns
$t_r$	rise time		-	300	-	ns
$t_{on}$	turn-on time		-	320	-	ns
$t_s$	storage time		-	830	-	ns
$t_f$	fall time		-	470	-	ns
$t_{off}$	turn-off time		-	1300	-	ns
$f_T$	transition frequency		$V_{CE} = 10\text{ V}; I_C = 100\text{ mA}; f = 100\text{ MHz};$ $T_{amb} = 25\text{ }^\circ\text{C}$	-	140	-
$C_c$	collector capacitance	$V_{CB} = 10\text{ V}; I_E = 0\text{ A}; i_e = 0\text{ A}; f = 1\text{ MHz};$ $T_{amb} = 25\text{ }^\circ\text{C}$	-	11	-	pF



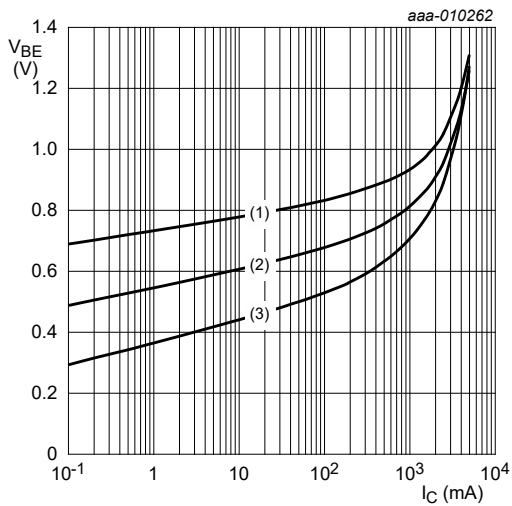
$V_{CE} = 10\text{ V}$   
 (1)  $T_{amb} = 100\text{ }^\circ\text{C}$   
 (2)  $T_{amb} = 25\text{ }^\circ\text{C}$   
 (3)  $T_{amb} = -55\text{ }^\circ\text{C}$

**Fig. 4. DC current gain as a function of collector current; typical values**



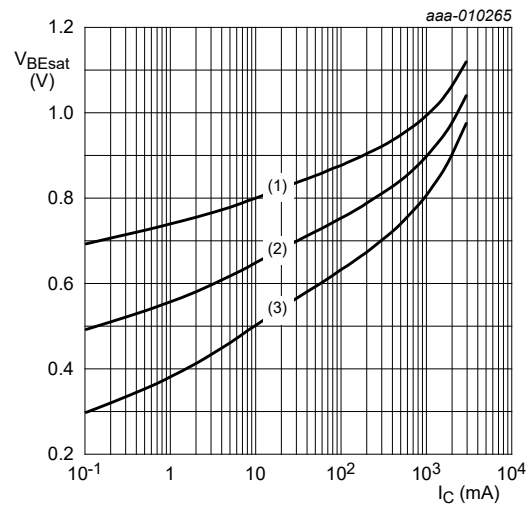
$T_{amb} = 25\text{ }^\circ\text{C}$

**Fig. 5. Collector current as a function of collector-emitter voltage; typical values**



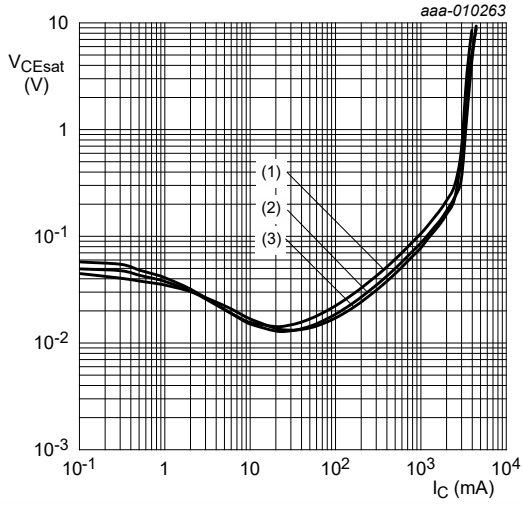
$V_{CE} = 2\text{ V}$   
 (1)  $T_{amb} = -55\text{ }^\circ\text{C}$   
 (2)  $T_{amb} = 25\text{ }^\circ\text{C}$   
 (3)  $T_{amb} = 100\text{ }^\circ\text{C}$

**Fig. 6. Base-emitter voltage as a function of collector current; typical values**



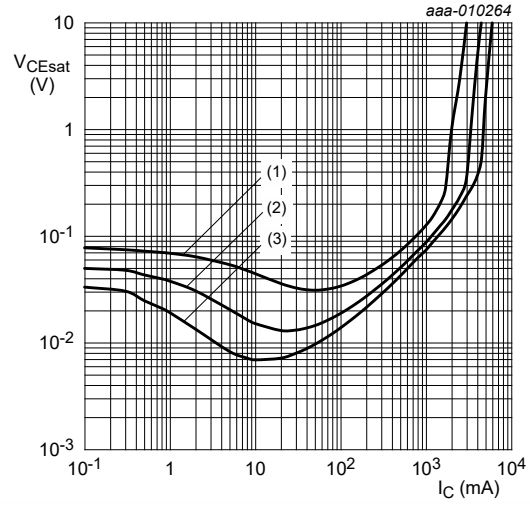
$I_C/I_B = 20$   
 (1)  $T_{amb} = -55\text{ }^\circ\text{C}$   
 (2)  $T_{amb} = 25\text{ }^\circ\text{C}$   
 (3)  $T_{amb} = 100\text{ }^\circ\text{C}$

**Fig. 7. Base-emitter saturation voltage as a function of collector current; typical values**



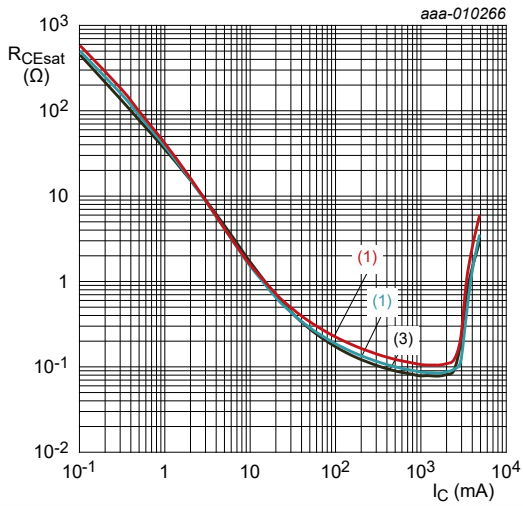
$I_C/I_B = 20$   
 (1)  $T_{amb} = 100\text{ }^\circ\text{C}$   
 (2)  $T_{amb} = 25\text{ }^\circ\text{C}$   
 (3)  $T_{amb} = -55\text{ }^\circ\text{C}$

Fig. 8. Collector-emitter saturation voltage as a function of collector current; typical values



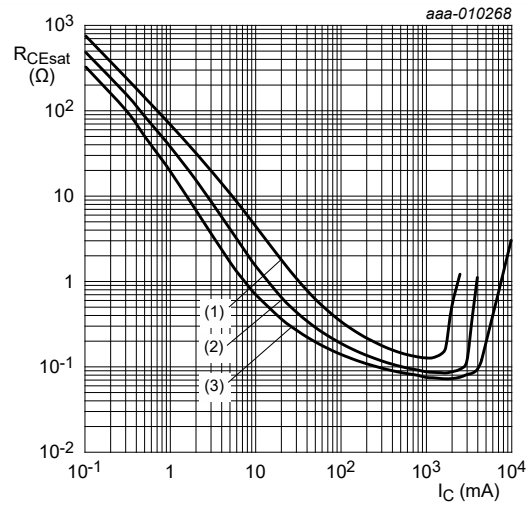
$T_{amb} = 25\text{ }^\circ\text{C}$   
 (1)  $I_C/I_B = 50$   
 (2)  $I_C/I_B = 20$   
 (3)  $I_C/I_B = 10$

Fig. 9. Collector-emitter saturation voltage as a function of collector current; typical values



$I_C/I_B = 20$   
 (1)  $T_{amb} = 100\text{ }^\circ\text{C}$   
 (2)  $T_{amb} = 25\text{ }^\circ\text{C}$   
 (3)  $T_{amb} = -55\text{ }^\circ\text{C}$

Fig. 10. Collector-emitter saturation resistance as a function of collector current; typical values



$T_{amb} = 25\text{ }^\circ\text{C}$   
 (1)  $I_C/I_B = 50$   
 (2)  $I_C/I_B = 20$   
 (3)  $I_C/I_B = 10$

Fig. 11. Collector-emitter saturation resistance as a function of collector current; typical values



### 11. Test information

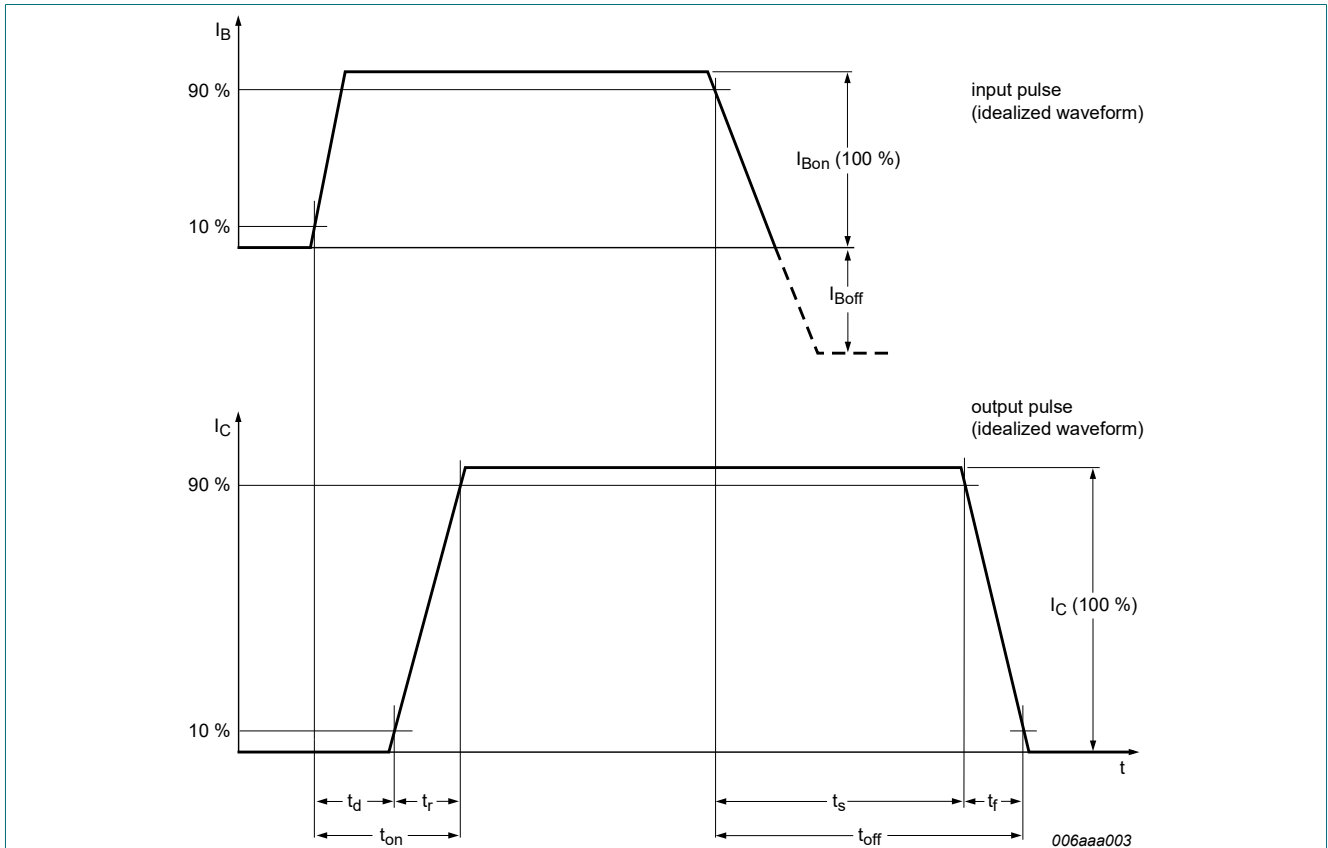


Fig. 12. BISS transistor switching time definition

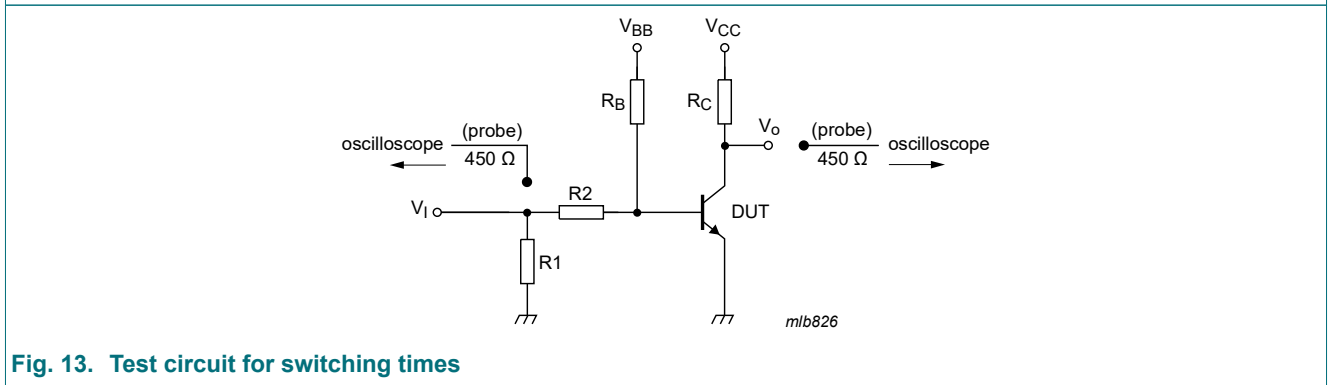


Fig. 13. Test circuit for switching times

### Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline

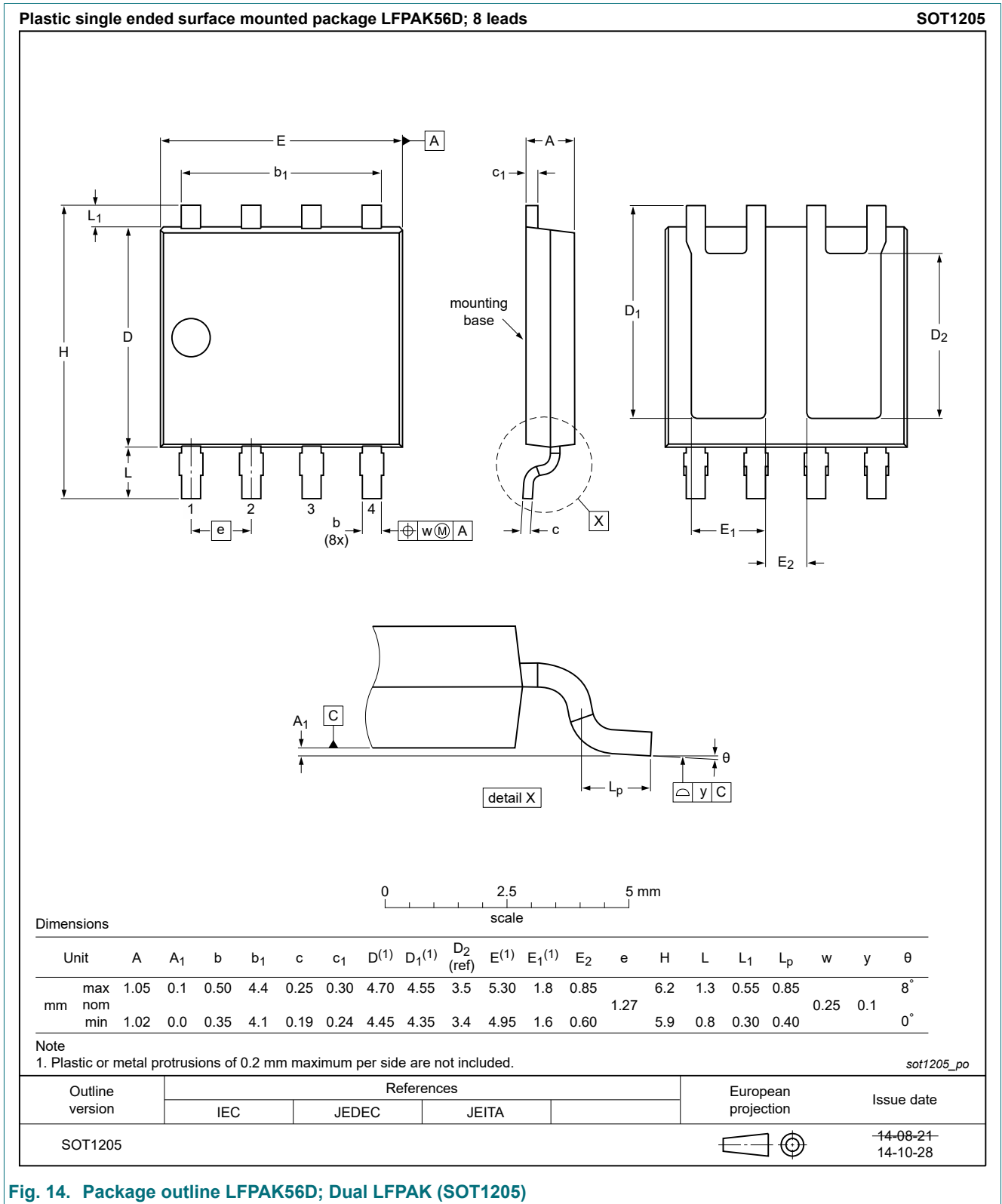


Fig. 14. Package outline LFAK56D; Dual LFAK (SOT1205)

### 13. Soldering

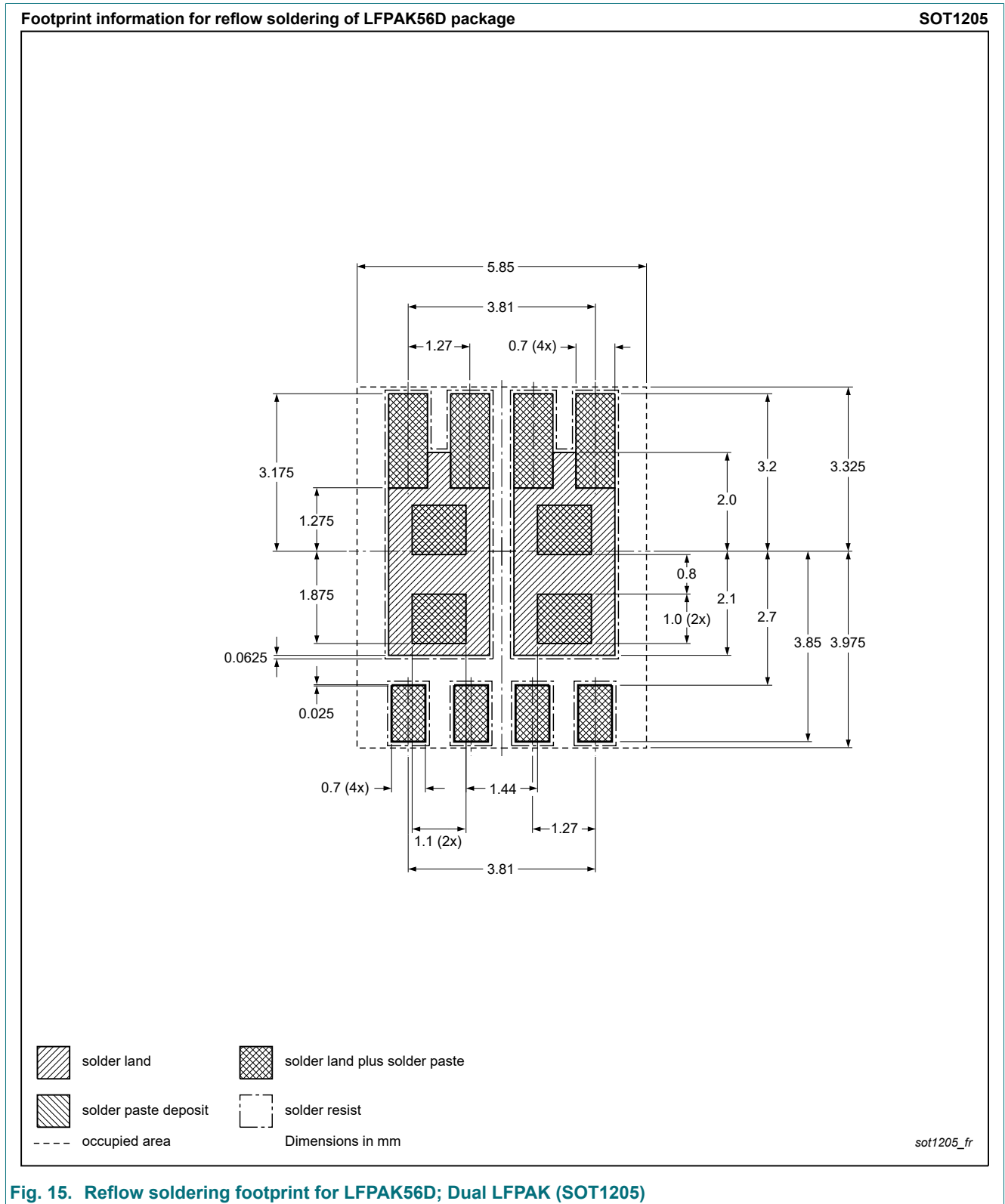


Fig. 15. Reflow soldering footprint for LFPAK56D; Dual LFPAK (SOT1205)

## 14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PHPT610030NK v.2	20200910	Product data sheet	-	PHPT610030NK v.1
Modifications:	• Characteristics: Figures 6, 7, 8 and 10 corrected			
PHPT610030NK v.1	20141020	Product data sheet	-	-

## 15. Legal information

### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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